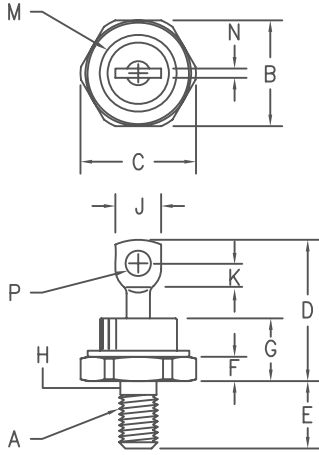


# Silicon Power Rectifier S/R38 Series



- Notes:
- 1/4-28 UNF-3A
  - Full threads within 2 1/2 threads
  - For Reverse Polarity add R to Part Number  
Standard Polarity: Stud is Cathode  
Reverse polarity: Stud is Anode

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	---	---	---	---	1
B	.667	.687	16.95	17.44	
C	---	.793	---	20.14	
D	---	1.00	---	25.40	
E	.422	.453	10.72	11.50	
F	.115	.200	2.93	5.08	
G	---	.450	---	11.43	
H	.220	.249	5.59	6.32	2
J	.250	.375	6.35	9.52	
K	.156	---	3.97	---	
M	---	.667	---	16.94	Dia
N	---	.080	---	2.03	
P	.140	.175	3.56	4.44	Dia

D0203AB (D05)

Microsemi Catalog Number	Standard	Reverse	Peak Reverse Voltage
S3820		R3820	200V
S3840		R3840	400V
S3860		R3860	600V
S3880		R3880	800V
S38100		R38100	1000V
S38120		R38120	1200V

- Glass to metal construction
- Highest current DO-5 available
- Glass passivated die
- 1800 amps surge rating
- VRRM to 1200V

## Electrical Characteristics

Average forward current	IF(AV) 100 Amps	TC = 144°C, half sine wave, RθJC = 0.5°C/W
Maximum surge current	IFSM 1800 Amps	8.3ms, half sine, TJ = 200°C
Max I <sup>2</sup> t for fusing	I <sup>2</sup> t 13440 A <sup>2</sup> s	
Max peak forward voltage	VFM 1.15 Volts	IFM = 200A: TJ = 25°C*
Max peak reverse current	IRM 25 μA	VRRM, TJ = 25°C
Max peak reverse current	IRM 3.0 mA	VRRM, TJ = 150°C
Max Recommended Operating Frequency	10kHz	

\*Pulse test: Pulse width 300 μsec. Duty cycle 2%

## Thermal and Mechanical Characteristics

Storage temperature range	TSTG	-65°C to 200°C
Operating junction temp range	TJ	-65°C to 200°C
Maximum thermal resistance	RθJC	0.5°C/W Junction to Case
Mounting torque		25-30 inch pounds
Weight		.6 ounces (17 grams) typical

# S/R38

Figure 1  
Typical Forward Characteristics

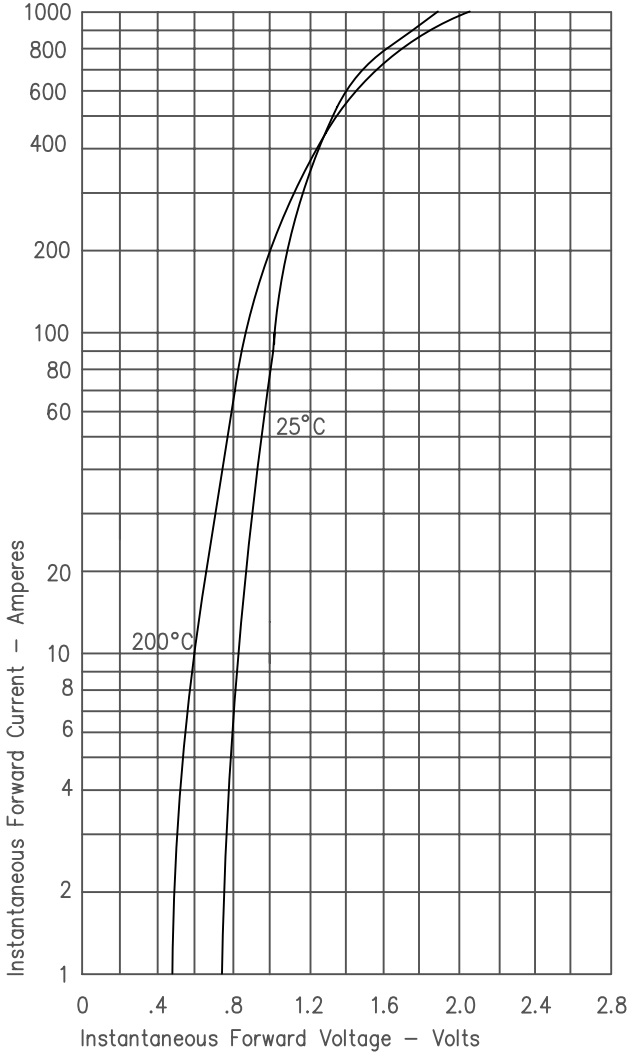


Figure 3  
Forward Current Derating

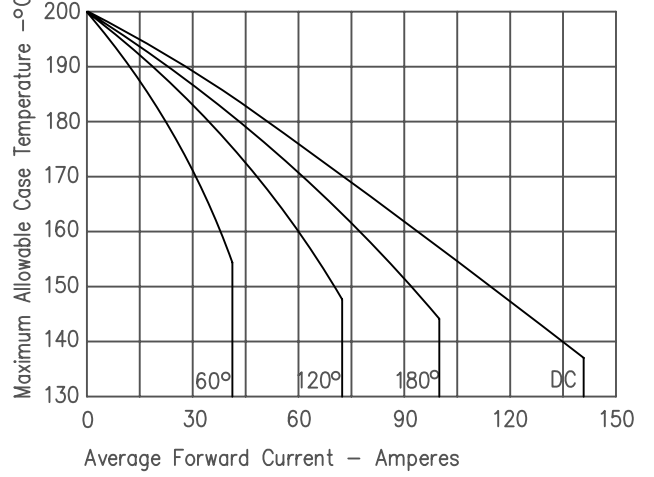


Figure 4  
Maximum Forward Power Dissipation

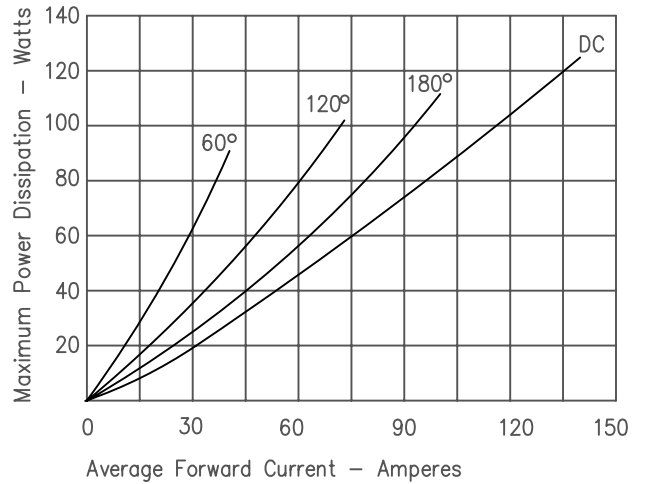


Figure 2  
Typical Reverse Characteristics

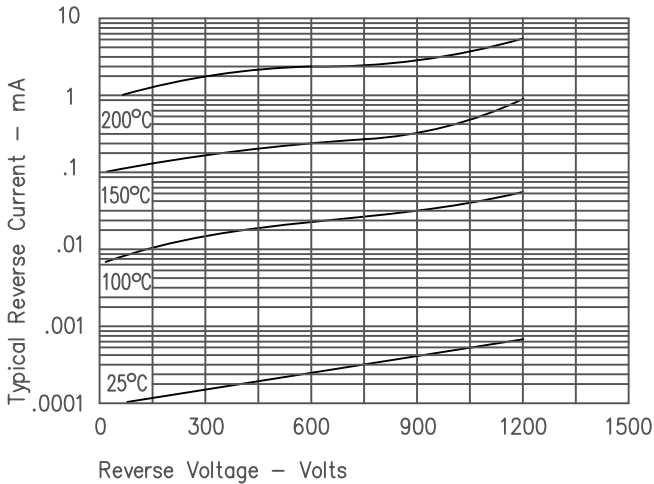


Figure 5  
Transient Thermal Impedance

